Rochester Electronics

Datasheet

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

ANALOG DEVICES

Quad Low-Power Voltage Comparators

PM-139/PM-139A/PM-239

FEATURES

- **Single or Dual Supply Operation**
- **Input Voltage Range Includes Ground**
- **Low Power Consumption (2mW/Comparator)**
- **Low Input Bias Current 25nA**
- **Low Input Offset Current ..... ±5nA**
- **Low Offset Voltage ..... ±2mV**
- **Low Output Saturation Voltage (250mV @ 4mA)**
- **Logic Outputs Compatible with TTL, DTL, ECL, MOS, and CMOS**
- **Directly Replaces LM139 and LM139A Comparators**
- **Available in Die Form**

ORDERING INFORMATION †

+25°C V_{OS} (mV)	PACKAGE DIP 14-PIN	PACKAGE LCC 20-CONTACT	OPERATING TEMPERATURE RANGE
±2*	PM139AY*	PM139ARC/883	MIL
±5*	PM139Y*	–	MIL
±5	PM239P	–	XIND

* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

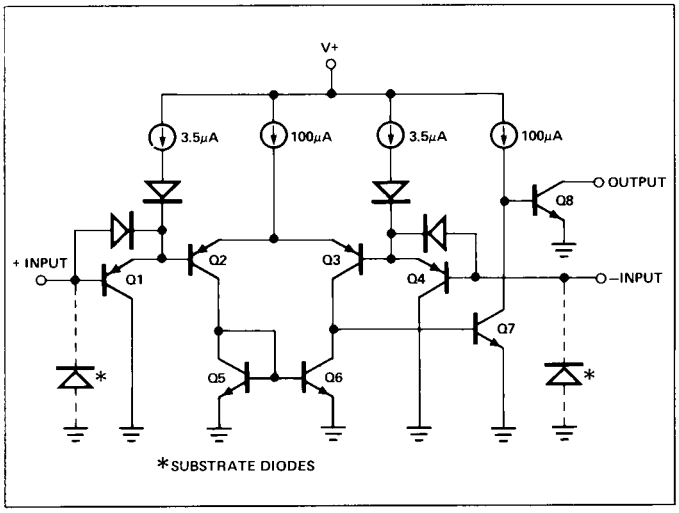
JAN ORDERING INFORMATION

JAN PART NUMBER	DESCRIPTION
JM38510/11201BCA	PM139Y5/38510 LEVEL B
JM38510/11201BCB	PM139Y2/38510 LEVEL B
JM38510/11201SCA*	PM139Y5/38510 LEVEL S

Table above is for MIL-M-38510 processing. Refer to 11201 slash sheet for electrical processing parameters.

* Undergoing Part I qualification. Consult ADI for availability.

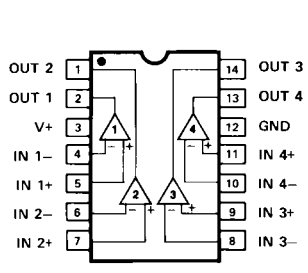
SIMPLIFIED SCHEMATIC (ONE COMPARATOR)



GENERAL DESCRIPTION

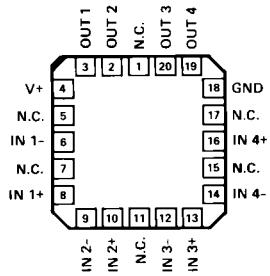
The PM-139 has four independent voltage comparators, each with precision DC specifications. Low offset voltage, bias current, power consumption and output saturation voltage are offered in a design that features single power supply operation. The input voltage range includes ground for convenient single supply operation. The 2mA power supply current, independent of supply voltage – coupled with the single supply operation, makes this comparator ideal for low power applications. Open collector outputs allow maximum applications flexibility.

PIN CONNECTIONS



14-PIN HERMETIC DIP (Y-Suffix)

14-PIN PLASTIC DIP (P-Suffix)



PM-139ARC/883 LCC PACKAGE (RC-Suffix)

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V+ ..... 36V or ±18V
Differential Input Voltage 36V
Input Voltage ..... –0.3V to +36V
Derate Above 100°C ..... 10mW/°C
Output Short-Circuit to Ground ..... Continuous
Input Current (V_{IN} < –0.3V) 50mA
Operating Temperature Range
PM-139A/139/139ARC ..... –55°C to +125°C
PM-239P ..... –40°C to +85°C
Storage Temperature Range ..... –65°C to +150°C
Lead Temperature (Soldering, 60 sec) ..... 300°C
Junction Temperature ..... +150°C

PACKAGE TYPE	Θ_{JA} (Note 1)	Θ_{JC}	UNITS
14-Pin Hermetic DIP (Y)	110	26	°C/W
14-Pin Plastic DIP (P)	90	47	°C/W

NOTE:

1. Θ_{JA} is specified for worst case mounting conditions, i.e., Θ_{JA} is specified for device in socket for CerDIP and P-DIP packages.

ELECTRICAL CHARACTERISTICS at V+ = +5V, T_A = 25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-139A MIN	PM-139A TYP	PM-139A MAX	PM-139/239 MIN	PM-139/239 TYP	PM-139/239 MAX	UNITS
Input Offset Voltage	V_{OS}	(Note 1)	—	1	2	—	2	5	mV
Input Bias Current	I_B	$I_{IN}(+)$ or $I_{IN}(-)$ with Output in Linear Range	—	25	100	—	25	100	nA
Input Offset Current	I_{OS}	$I_{IN}(+)$ or $I_{IN}(-)$	—	3	25	—	3	25	nA
Input Common-Mode Voltage Range	CMVR	(Notes 2, 5, 6)	0	—	3.5	0	—	3.5	V
Supply Current	I_S	$R_L = \infty$ on all Comparators V+ = 30V	—	0.8	2	—	0.8	2	mA
Voltage Gain	A_{VO}	$R_L \geq 15k\Omega$, V+ = 15V (To support large V_O swing) (Note 5)	50	200	—	50	200	—	V/mV
Large-Signal Response Time	t_r	V_{IN} = TTL Logic Swing, V_{REF} = 1.4V, V_{RL} = 5V, R_L = 5.1kΩ, (Note 4)	—	300	—	—	300	—	ns
Response Time	t_r	V_{RL} = 5V, R_L = 5.1kΩ (Notes 3, 4)	—	1.3	—	—	1.3	—	μs
Output Sink Current	I_{SINK}	$V_{IN}(-) \geq 1V$, $V_{IN}(+) = 0$, $V_O \leq 1.5V$	6	16	—	6	16	—	mA
Saturation Voltage	V_{OL}	$V_{IN}(-) \geq 1V$, $V_{IN}(+) = 0$, $I_{SINK} \leq 4mA$	—	250	400	—	250	400	mV
Output Leakage Current	I_{LEAK}	$V_{IN}(+) \geq 1V$, $V_{IN}(-) = 0$, V_O = 30V	—	0.1	—	—	0.1	—	nA

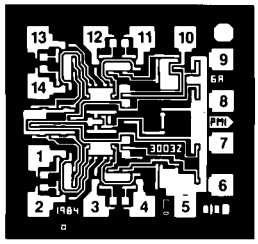
ELECTRICAL CHARACTERISTICS at V+ = +5V, −55°C ≤ T_A ≤ +125°C for PM-139A and PM-139, −40°C ≤ T_A ≤ +85°C for PM-239, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-139A MIN	PM-139A TYP	PM-139A MAX	PM-139/239 MIN	PM-139/239 TYP	PM-139/239 MAX	UNITS
Input Offset Voltage	V_{OS}	(Note 1)	—	—	4	—	—	9	mV
Input Offset Current	I_{OS}	$I_{IN}(+)$ or $I_{IN}(-)$	—	—	100	—	—	100	nA
Input Bias Current	I_B	$I_{IN}(+)$ OR $I_{IN}(-)$ with Output in Linear Range	—	—	300	—	—	300	nA
Input Common-Mode Voltage Range	CMVR	(Notes 3, 5)	0	—	V+ −2	0	—	V+ −2	V
Saturation Voltage	V_{OL}	$V_{IN}(-) \geq 1V$, $V_{IN}(+) = 0$, $I_{SINK} \leq 4mA$	—	—	700	—	—	700	mV
Output Leakage Current	I_{LEAK}	$V_{IN}(+) \geq 1V$, $V_{IN}(-) = 0$, V_O = 30V	—	—	1	—	—	1	μA
Differential Input Voltage		Keep All V_{IN}'s ≥ 0V	—	—	36	—	—	36	V

NOTES:

1. At output switch point, V_O = 1.4V, R_S = 0Ω with V+ from 5V, and over the full input common-mode range (0V to V+ −1.5V).
2. The input common-mode voltage or either input voltage signal should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V+ −1.5V, but either or both inputs can go to +30V without damage.
3. The response time specified is for a 100mV input step with 5mV overdrive. For larger overdrive signals 300ns can be obtained. See characteristics section.
4. Sample tested.
5. Guaranteed by design.
6. Positive CMVR limit equals V+ −1.5V for supply voltages other than 5V.

DICE CHARACTERISTICS



1. OUTPUT (2)
2. OUTPUT (1)
3. POSITIVE SUPPLY
4. INVERTING INPUT (1)
5. NONINVERTING INPUT (1)
6. INVERTING INPUT (2)
7. NONINVERTING INPUT (2)
8. INVERTING INPUT (3)
9. NONINVERTING INPUT (3)
10. INVERTING INPUT (4)
11. NONINVERTING INPUT (4)
12. GROUND (SUBSTRATE)
13. OUTPUT (4)
14. OUTPUT (3)

DIE SIZE 0.051 × 0.048 inch, 2448 sq. mils
(1.295 × 1.220 mm, 1.58 sq. mm)

WAFER TEST LIMITS at V+ = +5V, T_A = 25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-139N LIMIT	UNITS
Input Offset Voltage	V_{OS}	$R_S = 0\Omega$, $R_L = 5.1k\Omega$ V_O = 1.4V, (Note 1)	2	mV MAX
Input Offset Current	I_{OS}	$I_{IN}(+) - I_{IN}(-)$ $R_L = 5.1k\Omega$ V_O = 1.4V	25	nA MAX
Input Bias Current	I_B	$I_{IN}(+)$ or $I_{IN}(-)$, (Note 1)	100	nA MAX
Voltage Gain	A_V	$R_L \geq 15k\Omega$, V+ = 15V, (Note 3)	50	V/mV MIN
Input Voltage Range	CMVR	(Notes 2, 3)	V+ − 1.5	V MAX
Common-Mode Rejection Ratio	CMRR	(Note 4)	60.5	dB MIN
Power Supply Rejection Ratio	PSRR	V+ = 5V to +18V	60.5	dB MIN
Saturation Voltage	V_{OL}	$V_{IN}(-) \geq 1V$, $V_{IN}(+) = 0$, $I_{SINK} \leq 4mA$	400	mV MAX
Output Sink Current	I_{SINK}	$V_{IN}(-) \geq 1V$, $V_{IN}(+) = 0$, $V_O \leq 1.5V$	6	mA MIN
Output Leakage Current	I_{LEAK}	$V_{IN}(+) \geq 1V$, $V_{IN}(-) = 0$, V_O = 30V	500	nA MAX
Supply Current	I+	$R_L = \infty$, All Comps V+ = 30V	2	mA MAX

NOTES:
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

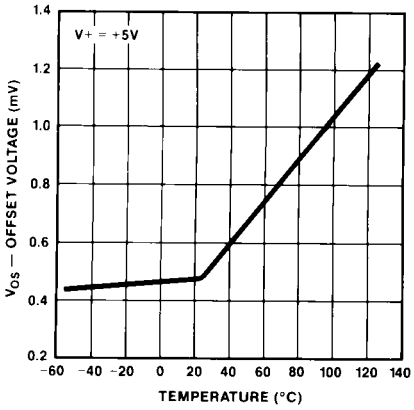
TYPICAL ELECTRICAL CHARACTERISTICS at V+ = +5V, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-139N TYPICAL	UNITS
Large-Signal Response Time	t_r	V_{IN} = TTL Logic Swing V_{REF} = 1.4V, (Note 5) V_{RL} = 5V, $R_L = 5.1k\Omega$	600	ns
Small-Signal Response Time	t_r	V_{IN} = 100mV Step, (Note 5) 5mV Overdrive V_{RL} = 5V, $R_L = 5.1k\Omega$	1.3	μs

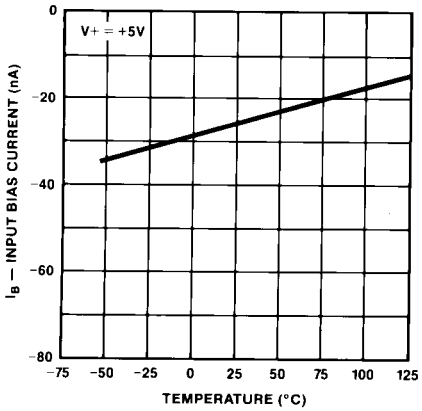
NOTES:
1. At output switch point, V_O = 1.4V, $R_S = 0\Omega$ with V+ from 5V; and over the full input common-mode range (0V to V+ − 1.5V).
2. The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V+ − 1.5V, but either or both inputs can go to +30V without damage.
3. Guaranteed by design.
4. $R_L \geq 15k\Omega$. V_{CM} = 1.5V to 13.5V, V+ = 15V.
5. Sample tested.

TYPICAL PERFORMANCE CHARACTERISTICS

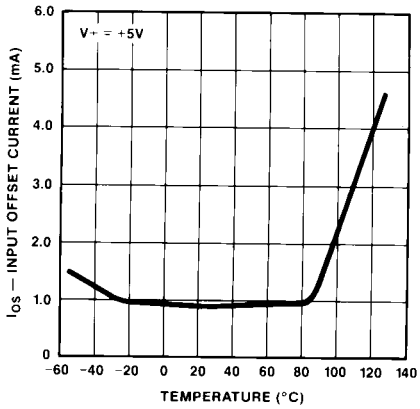
OFFSET VOLTAGE vs TEMPERATURE



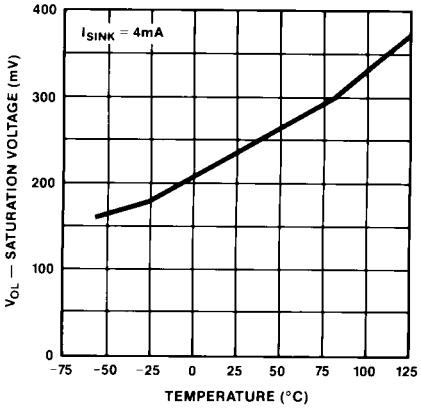
INPUT BIAS CURRENT vs TEMPERATURE



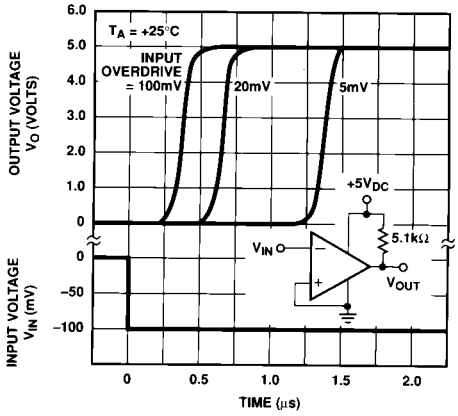
INPUT OFFSET CURRENT vs TEMPERATURE



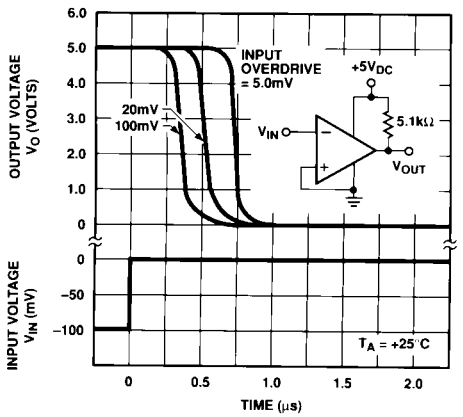
SATURATION VOLTAGE vs TEMPERATURE



RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES — POSITIVE TRANSITION

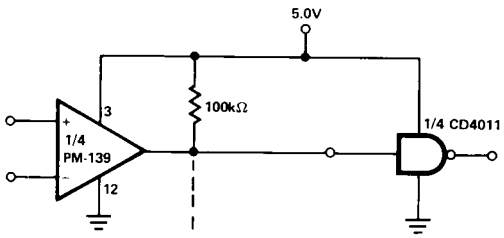


RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES — NEGATIVE TRANSITION

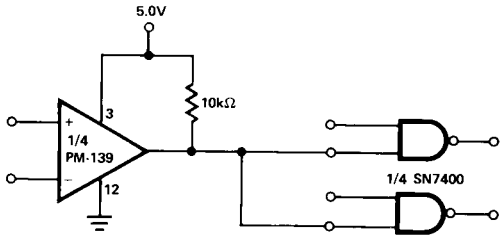


TYPICAL INTERFACE

DRIVING CMOS

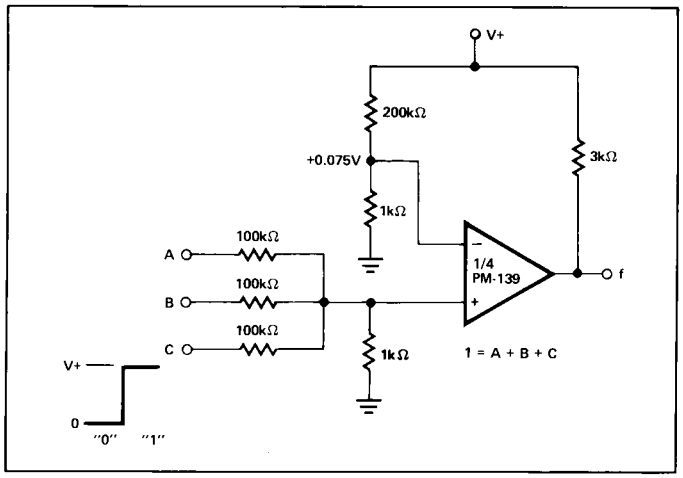


DRIVING TTL

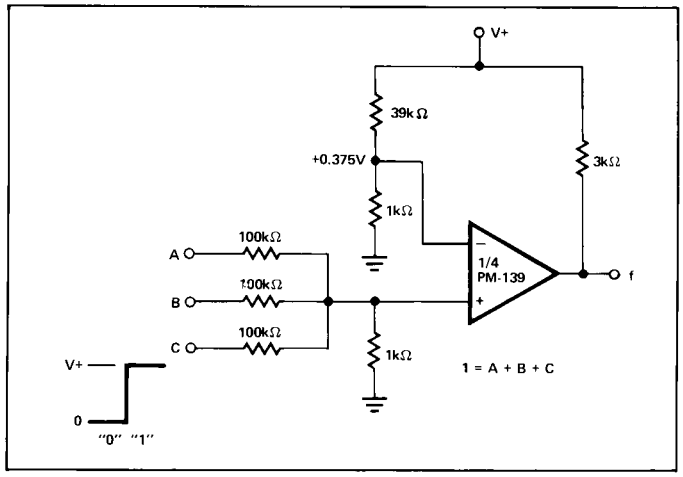


TYPICAL APPLICATIONS

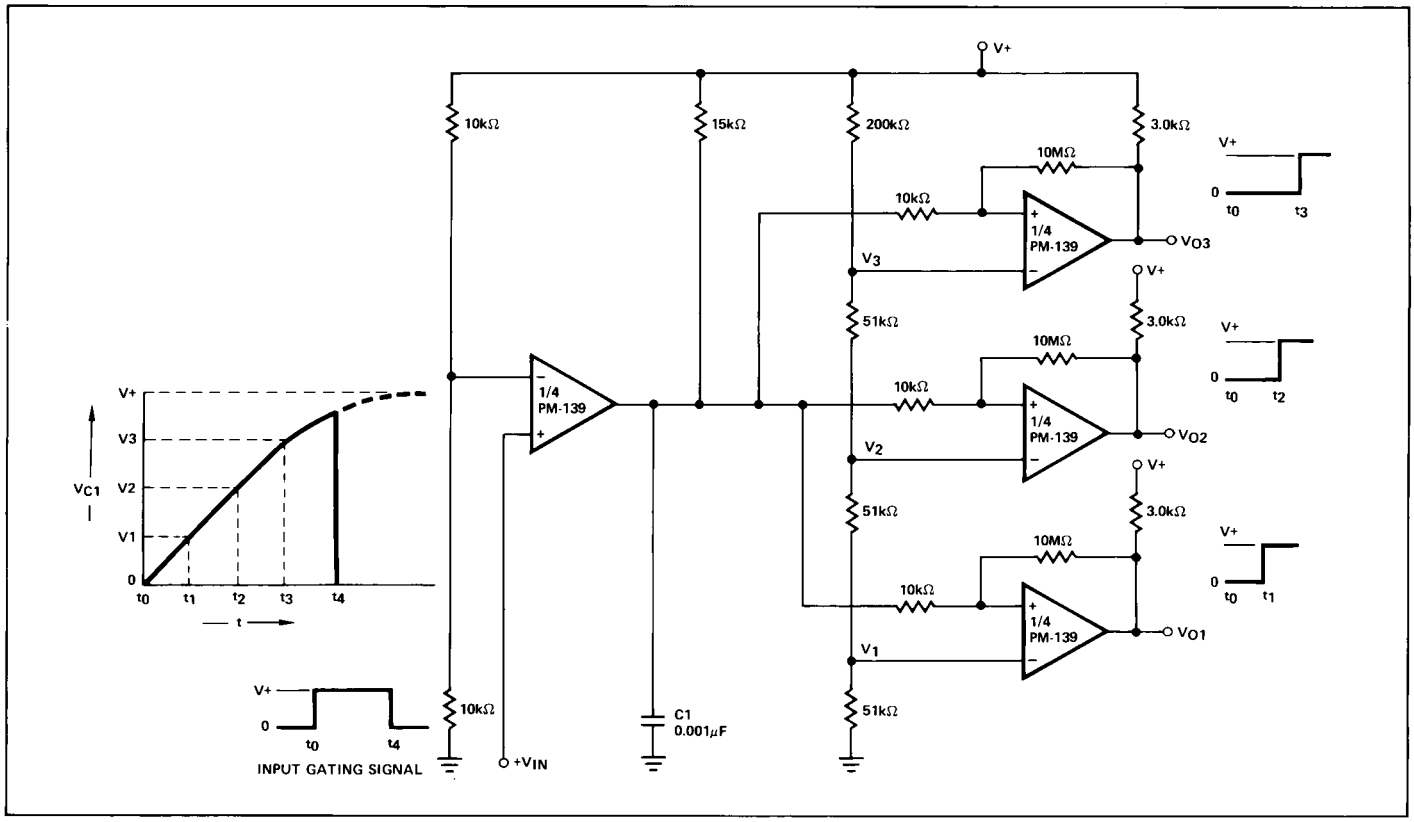
OR GATE



AND GATE

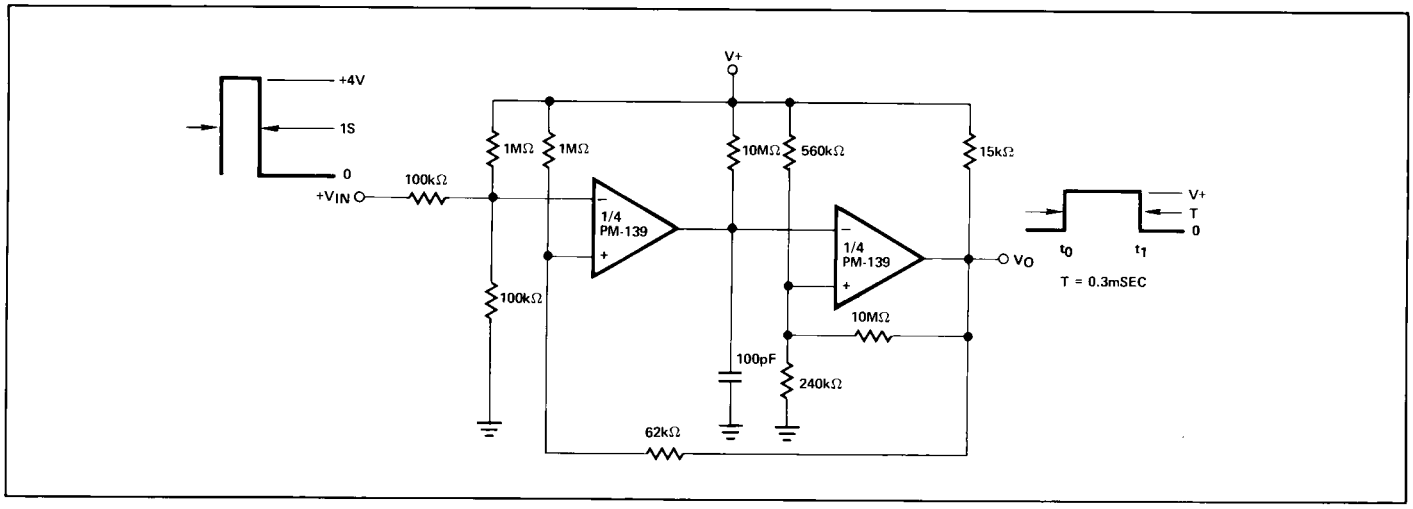


TIME DELAY GENERATOR

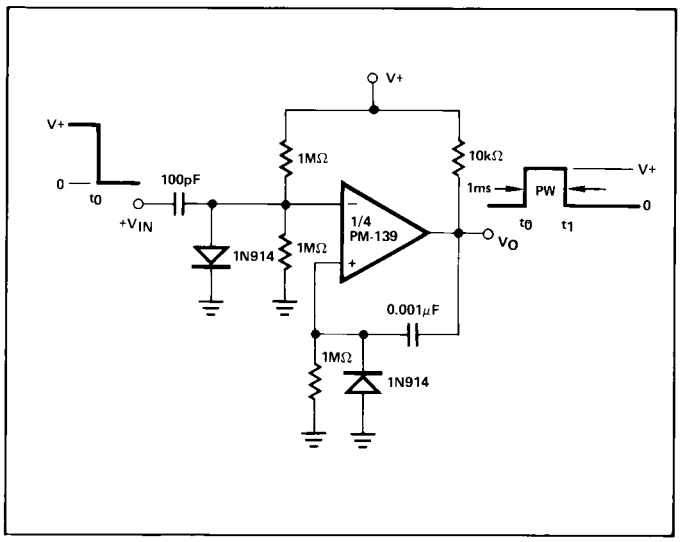


TYPICAL APPLICATIONS

ONE-SHOT MULTIVIBRATOR WITH INPUT LOCK-OUT



ONE-SHOT MULTIVIBRATOR



BURN-IN CIRCUIT